TOSHIBA Insulated Gate Bipolar Transistor Silicon N Channel IGBT

GT30J121

High Power Switching Applications

Fast Switching Applications

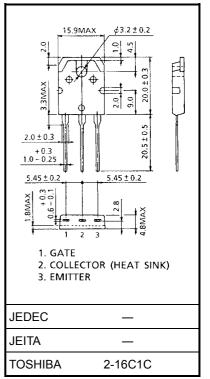
- The 4th generation
- Enhancement-mode
- Fast switching (FS): Operating frequency up to 50 kHz (reference) High speed: $t_f = 0.05 \ \mu s$ (typ.) Low switching loss: $E_{on} = 1.00 \ mJ$ (typ.)

: E_{off} = 0.80 mJ (typ.)

• Low saturation voltage: VCE (sat) = 2.0 V (typ.)

Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	600	V	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	Ι _C	30	A	
	1 ms	I _{CP}	60		
Collector power dissipation (Tc = 25°C)		Pc	170	W	
Junction temperature		Тј	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Maximum Ratings (Ta = 25°C)



Weight: 4.6 g (typ.)

Thermal Characteristics

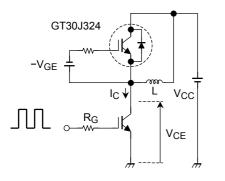
Characteristics	Symbol	Max	Unit
Thermal resistance	R _{th (j-c)}	0.735	°C/W

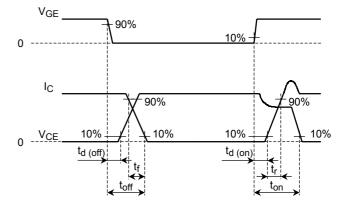
Unit: mm

Electrical Characteristics (Ta = 25°C)

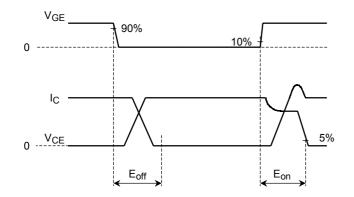
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	urrent	I _{GES}	V_{GE} = ±20 V, V_{CE} = 0		_	±500	nA
Collector cut-off current		ICES	V _{CE} = 600 V, V _{GE} = 0		_	1.0	mA
Gate-emitter cut-off voltage		V _{GE (OFF)}	I_C = 3 mA, V_{CE} = 5 V	3.5	—	6.5	V
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 30 A, V _{GE} = 15 V	_	2.0	2.45	V
Input capacitance		Cies	V_{CE} = 10 V, V_{GE} = 0, f = 1 MHz	_	4650	—	pF
Switching time	Turn-on delay time	t _{d (on)}	Inductive Load V_{CC} = 300 V, I _C = 30 A V_{GG} = +15 V, R _G = 24 Ω (Note 1) (Note 2)	_	0.09	—	μs ·
	Rise time	tr		_	0.07	_	
	Turn-on time	t _{on}			0.24	_	
	Turn-off delay time	t _{d (off)}		_	0.30	_	
	Fall time	t _f		_	0.05	_	
	Turn-off time	t _{off}		_	0.43	_	
Switching loss	Turn-on switching loss	E _{on}		_	1.00	_	- mJ
	Turn-off switching loss	E _{off}		—	0.80	—	

Note 1: Switching time measurement circuit and input/output waveforms

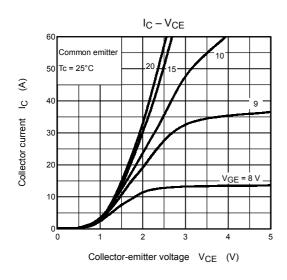


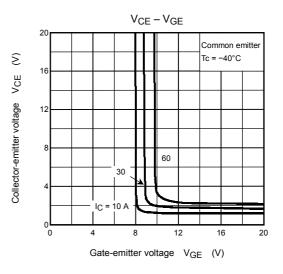


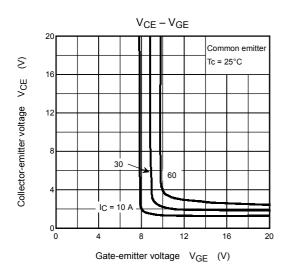
Note 2: Switching loss measurement waveforms

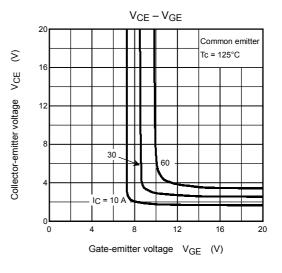


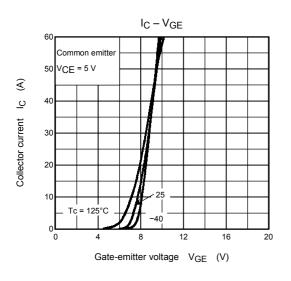
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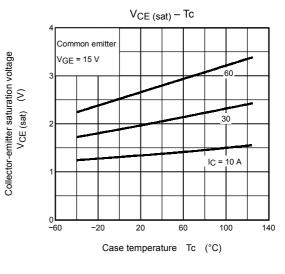




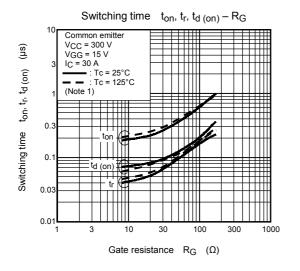


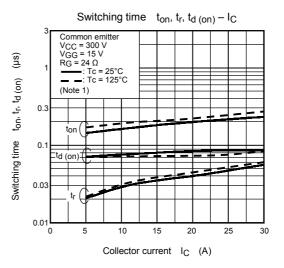




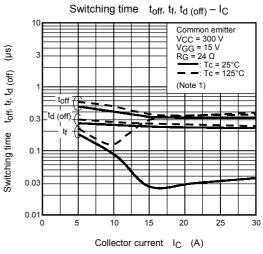


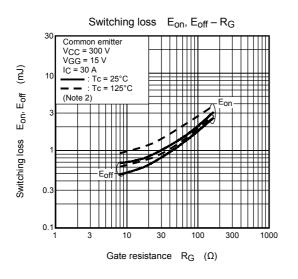
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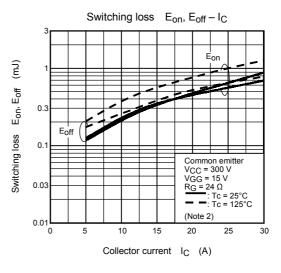




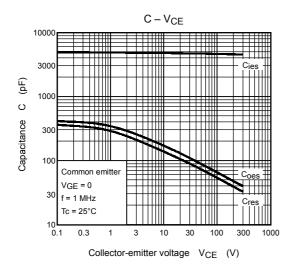
Switching time $t_{off}, t_{f}, t_{d (off)} - R_G$ 10 Common emitter $V_{CC} = 300 V$ $V_{GG} = 15 V$ $I_{C} = 30 A$ $\therefore T_{C} = 25^{\circ}C$ $\therefore T_{C} = 125^{\circ}C$ (srl) 3 toff, tf, td (off) (Note 1) 0.3 toff d (off ŧ Switching time 0.1 +## 0.03 tf 0.01 300 3 30 1000 10 100 Gate resistance R_G (Ω)

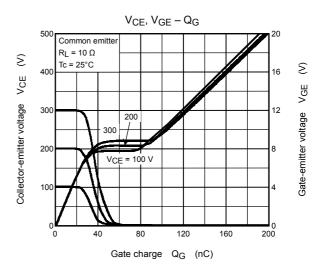




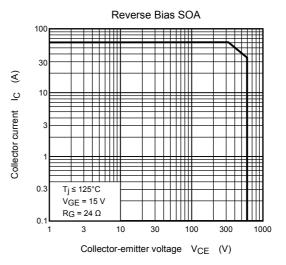


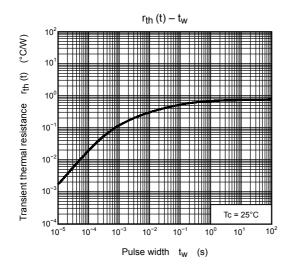
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Safe Operating Area 100 IC max (pulsed)* IC max (continuous) 30 100 € 10 <u>ں</u> DC operation Collector current Single pulse $Tc = 25^{\circ}C$ Curves must be derated linearly 0.3 with increase in temperature. 0.1 3 10 30 300 1000 100 Collector-emitter voltage V_{CE} (V)





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